PATENT COOPERATION TREATY



PCT

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

AU6^0 8 2005

(PCT Article 36 and Rule 70)

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Applicant's or agent's file reference BIF023239/DM	FOR FURTHER ACTI	^ XI	cation of Transmittal of International Examination Report (Form PCT/IPEA/416)						
International application No.	International filing date (a		Priority date (day/month/year)						
PCT/FR2003/003256	31 octobre 2003 (3	31.10.2003)	07 novembre 2002 (07.11.2002)						
International Patent Classification (IPC) or national classification and IPC H01L 21/762, 21/265									
Applicant COMMISSARIAT A L'ENERGIE ATOMIQUE									
 This international preliminary examination report has been prepared by this International Preliminary Examining Authority and is transmitted to the applicant according to Article 36. 									
2. This REPORT consists of a total of5 sheets, including this cover sheet.									
This report is also accompanied by ANNEXES, i.e., sheets of the description, claims and/or drawings which have been amended and are the basis for this report and/or sheets containing rectifications made before this Authority (see Rule 70.16 and Section 607 of the Administrative Instructions under the PCT).									
These annexes consist of a total of sheets.									
This report contains indications relating to the following items:									
I Basis of the report									
II Priority	II Priority								
III Non-establishment	t of opinion with regard to r	ovelty, inventive	step and industrial applicability						
IV Lack of unity of in	vention								
V Reasoned statemen	Reasoned statement under Article 35(2) with regard to povelty, inventive step or industrial applicability:								
VI Certain documents	s cited								
VII Certain defects in	Contain defeats in the intermedianal continuity								
VIII Certain observations on the international application									
Date of submission of the demand	. Da	Date of completion of this report							
25 mars 2004 (25.03.2	2004)	14 February 2005 (14.02.2005)							
Name and mailing address of the IPEA/EP	Aı	Authorized officer							
Facsimile No.	Te	Telephone No.							

International application No.

PCT/FR2003/003256

I. Basis	I. Basis of the report							
1. This under	1. This report has been drawn on the basis of (Replacement sheets which have been furnished to the receiving Office in response to an invitation under Article 14 are referred to in this report as "originally filed" and are not annexed to the report since they do not contain amendments.):							
		the international	I application as	originally filed.				
	\boxtimes	the description,	pages	1-16	_, as originally filed,			
	<u></u>				_, filed with the demand,			
			pages					
			pages		, filed with the letter of			
	\boxtimes	the claims,	Nos	1-18	_ , as originally filed,			
	<u> </u>				, as amended under Article 19,			
					, filed with the demand,			
			Nos		, filed with the letter of,			
					, filed with the letter of			
	\boxtimes	the drawings,			_ , as originally filed,			
-	£				_ , filed with the demand,			
			sheets/fig		, filed with the letter of,			
					, filed with the letter of			
2. The a	mend	ments have resulte		٠.				
		the description,	pages					
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3.	This	report has been es	stablished as if	(some of) the am	nendments had not been made, since they have been considered a Supplemental Box (Rule 70.2(c)).			
	io po	Deyona me ansero)Sure as mou, a.	s indicated in the	: Supplemental Box (Kule 70.2(c)).			
4. Additi	ional (observations, if ne	ecessary:					
		,						

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YES

NO

1-8

V.	Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement						
1.	Statement						
	Novelty (N)	Claims	1-8	YES			
		Claims		NO			
	Inventive step (IS)	Claims	1-8	YES ·			
		Claims		NO NO			
}							

2. Citations and explanations

Industrial applicability (IA)

1. Reference is made to the following documents:

Claims

Claims

- D1: AGARWAL A ET AL: "EFFICIENT PRODUCTION OF SILICON-ON-INSULATOR FILMS BY CO-IMPLANTATION OF HE+ WITH H+" APPLIED PHYSICS LETTERS, AMERICAN INSTITUTE OF PHYSICS. NEW YORK, US, vol. 72, no. 9, 2 March 1998, pages 1086-1088, XP000742819 ISSN: 0003-6951
- D2: FR-A-2 774 510 (S O I TEC SILICON ON INSULATOR) 6
 August 1999
- D3: US-A-6 150 239 (TONG QIN-YI ET AL) 21 November 2000
- 2. The present application meets the requirements of PCT Article 33(1) since the subject matter of claims 1 and 17 meets the novelty and inventive step requirements (PCT Article 33(2) and (3)).
- 2.1 D1, which is considered the prior art document closest to the subject matter of claims 1 and 17, describes (the references in brackets are to that document):
- "principal" implantation in a substrate (see abstract, implantation of H);
- "secondary" implantation in the substrate, with a higher concentration than that of the "principal" species (see

abstract, implantation of He); and

- the triggering of the fracture along the "principal" depth (see page 1088, left-hand column, lines 15 to 19).
- 2.2 Therefore the subject matter of claims 1 and 17 differs from this known method and thin layer in that D1 does not describe the following features:
- "secondary" implantation to a "secondary" depth
 different from the "principal" depth;
- the "secondary" chemical species which is less efficient than the "principal" species for embrittling the substrate; and
- the **migration** of at least some of the "secondary" species to the vicinity of the "principal" depth.
- 2.3 Therefore the subject matter of claims 1 and 17 is novel (PCT Article 33(2)).
- 2.4 The problem addressed by the present invention can thus be considered that of obtaining a relatively thin embrittled area using a small number of implantations.
- 2.5 For the following reasons, the solution to this problem proposed in claims 1 and 17 of the present application is considered to involve an inventive step (PCT Article 33(3)):

None of the international search report citations suggests to a person skilled in the art that all the features of claims 1 and 17 be applied.

Although D2 and D3 describe a "principal" implantation and a "secondary" implantation in a substrate (D2: figure 4; D3: column 10, lines 8 to 38), D2 does not describe

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different levels of efficiency for embrittling the substrate since, in that document, the implanted elements are of the same type; and D3 does not describe the two elements being implanted to different depths.

It is not considered obvious for a person skilled in the art to combine the features known from D1, D2 and D3 and thus arrive at a method or thin layer as per claims 1 and 17.

- 2.6 Claims 1 and 17 of the present application are thus considered to involve an inventive step (PCT Article 33(3)).
- 3. Claims 2 to 16 are dependent on claim 1 and claim 18 is dependent on claim 17. Therefore these claims likewise meet the PCT novelty and inventive step requirements (PCT Article 33(2) and (3)).
- 4. The subject matter of claims 1 to 18 meets the requirements of PCT Article 33(4).